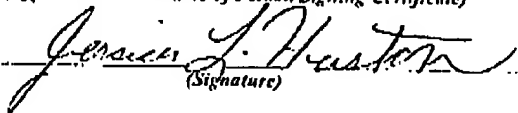


CERTIFICATE OF TRANSMISSION BY FACSIMILE (37 CFR 1.8)			Docket No.
Applicant(s): S. SUNDAR KUMAR IYER ET AL.			FIS920000372US1
Application No. 09/878,556	Filing Date 06/11/2001	Examiner J. CHEN	Group/Art Unit 2813
Invention: METHOD FOR FORMING VARIABLE OXIDE THICKNESS ACROSS SEMICONDUCTOR CHIPS			
<b>RECEIVED</b> <b>CENTRAL FAX CENTER</b> <b>SEP 12 2005</b>			
I hereby certify that this _____ <u>Transmittal and Amendment</u> _____ (Identify type of correspondence)			
is being facsimile transmitted to the United States Patent and Trademark Office (Fax. No. <u>571-273-8300</u> )			
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Applicant:	S. SUNDAR KUMAR IYER, ET AL.	)	
Serial No.:	09/878,556	)	Group Art Unit: 2813
Filed:	June 11, 2001	)	Examiner: Chen, J.
For:	METHOD OF FORMING VARIABLE OXIDE THICKNESS ACROSS SEMICONDUCTOR CHIPS	)	Confirmation No.: 3210

**RESPONSE TO OFFICE ACTION**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

In response to the Office Action mailed June 14, 2005, the Applicants submit the following remarks: